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(54) **LIQUID CRYSTAL DISPLAY APPARATUS HAVING LEVEL CONVERSION CIRCUIT**

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See application file for complete search history.

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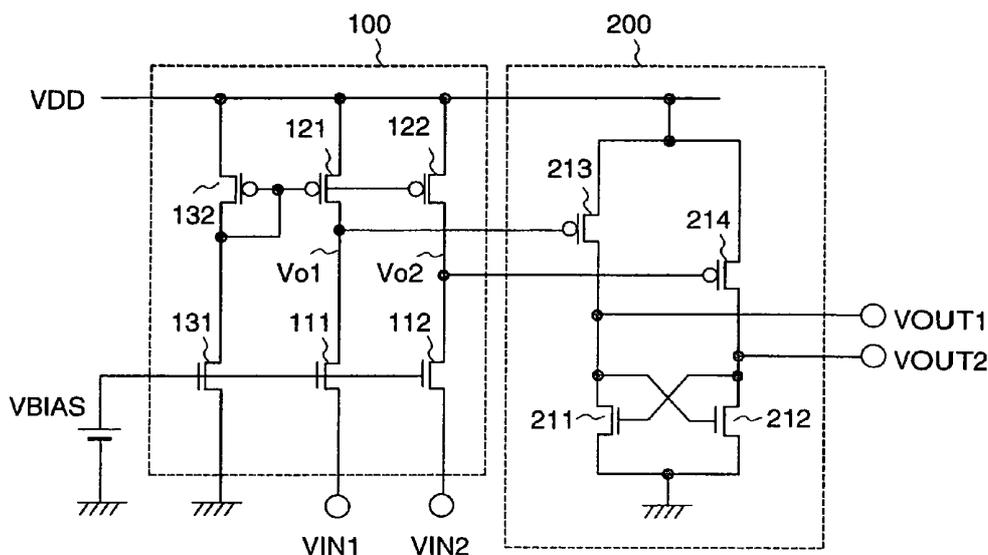
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(57) **ABSTRACT**

A liquid crystal display apparatus having a level conversion circuit in which a high speed operation can be attained and also a small transistor capacity can be obtained is provided. In the liquid crystal display apparatus, a signal circuit for driving pixel elements of a display unit and a scanning circuit are provided. The level conversion circuit is constituted of a first and a second transistors **111** and **112** in which a respective gate electrodes is connected to a first bias voltage power supply, and a third and a fourth transistors **121** and **122** in which a respective gate electrodes is connected to a second bias voltage power supply and a respective source electrodes is connected to a power supply.

**18 Claims, 5 Drawing Sheets**



US 7,460,100 B2

Page 2

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FIG. 3

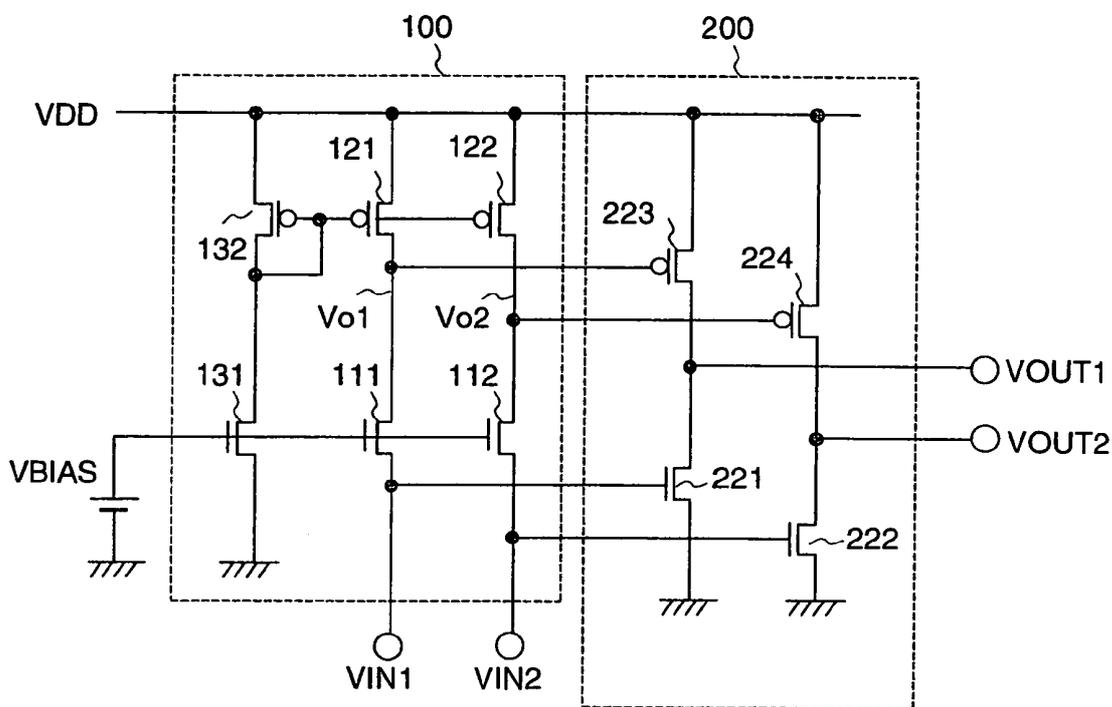
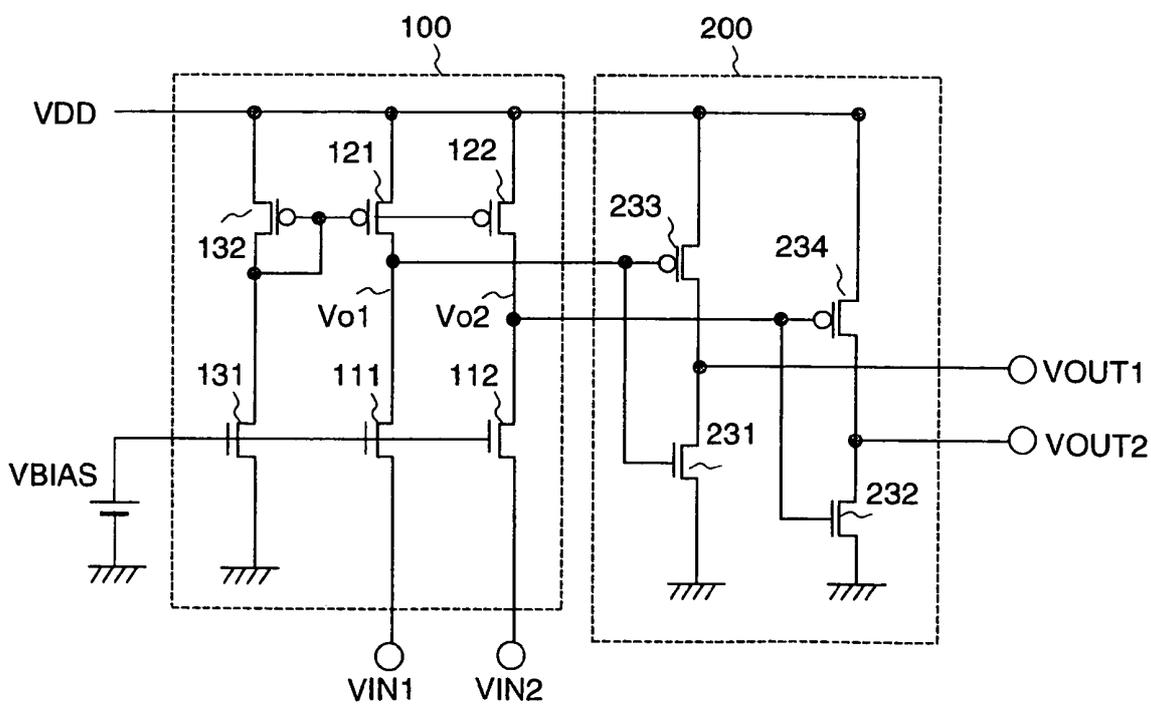


FIG. 4









## LIQUID CRYSTAL DISPLAY APPARATUS HAVING LEVEL CONVERSION CIRCUIT

### CROSS-REFERENCE TO RELATED APPLICATIONS

This is a continuation of application Ser. No. 10/797,013 filed 11 Mar. 2004, now U.S. Pat. No. 6,919,873, which is a continuation of application Ser. No. 10/150,952 filed 21 May 2002 and issued as U.S. Pat. No. 6,714,184 B2, which is a continuation of application Ser. No. 09/337,260 filed 22 Jun. 1999 and issued as U.S. Pat. No. 6,392,625 B1, the contents of all of which are incorporated herein by reference in their entirety.

### BACKGROUND OF THE INVENTION

The present invention relates to a liquid crystal display apparatus having a level conversion circuit in which a signal having a low voltage amplitude is converted to a signal having a high voltage amplitude; and, in particular, the invention relates to a level conversion circuit for use in a clock interface and a data interface of a liquid crystal display apparatus using thin-film transistors (TFT: Thin-Film Transistor).

A level conversion circuit of the type used in a clock interface and a data interface of a liquid crystal display apparatus is described in, for example JP-A 6-216753 and JP-A 6-283979. In the level conversion circuit shown in these publications, a thin-film transistor, such as a multi-crystallization silicon and a metal-oxide semiconductor (MOS: Metal-Oxide Semiconductor) having a mono-crystallization silicon, are employed. In such a level conversion circuit, an input signal having a low voltage amplitude is converted to an output signal having a high voltage amplitude for use in a drive circuit for the liquid crystal display apparatus.

The above-stated input signal has, for example, a voltage amplitude of 5 V or 3.3 V, such as used in a common LSI. Further, the above-stated output signal has, for example, a voltage amplitude of 12 V or 15 V, which corresponds to a power supply voltage of an interior circuit of the level conversion circuit.

As examples of this level conversion circuit, there are a differential input type level conversion circuit, which inputs a mutually reverse phase signal, and a single phase input type level conversion circuit, which inputs an independent signal. The differential input type level conversion circuit is used in a comparatively high speed clock interface, and the single phase input type level conversion circuit is used in a data interface.

FIG. 9 shows an example of the differential input type level conversion circuit described in JP-A 6-216753. This level conversion circuit 800 is constituted by a pair of input transistors 811 and 812, a pair of load transistors 813 and 814, a pair of constant current power supplies 815 and 816, and a pair of level shift transistors 817 and 818.

The respective input transistors 811 and 812 and the respective level shift transistors 817 and 818 are each provided as an N type TFT. The respective load transistors 813 and 814 are each provided as a P type TFT. In the level shift transistors 817 and 818, a drain electrode and a gate electrode are connected to each other and respective source electrodes are connected to input terminals VIN1 and VIN2. Further, to a connection point of the drain electrode and the gate electrode, the constant current power supplies 815 and 816 and the gate electrodes of the input transistors 811 and 812 are connected.

The respective source electrodes of the input transistors 811 and 812 are connected to ground and the respective drain electrodes of the input transistors 811 and 812 are connected to the respective output terminals VOUT1 and VOUT2. The respective drain electrodes of the load transistors 813 and 814 are connected respectively to output terminals VOUT1 and VOUT2. The respective gate electrodes of the load transistors 813 and 814 are connected respectively to the output terminals VOUT2 and VOUT1. The respective source electrodes of the load transistors 813 and 814 are connected to a power supply VDD.

In the level conversion circuit 800 connected in the above-described manner, the signals which are supplied at the input terminals VIN1 and VIN2 have a mutually reverse phase. Herein, the operation state of the level conversion circuit 800 will be explained on the assumption that the voltages which are inputted to the input terminals VIN1 and VIN2 are 3.3 V and 0 V, respectively, the voltage of the power supply VDD is 15 V, and a threshold voltage of the respective N type transistors is 2 V.

Since each of the level shift transistors 817 and 818 operates to increase the voltage level at the input terminals VIN1 and VIN2 with a threshold voltage, the voltages of 5.3 V and 2 V are applied respectively to the gate electrodes of the input transistors 811 and 812. As a result, the input transistor 811 presents a conductive state and the input transistor 812 presents a non-conductive state, respectively, and then the voltage of the output terminal VOUT1 becomes 0 V.

Since this output terminal VOUT1 is connected to the gate electrode of the load transistor 814, the load transistor 814 presents a conductive state and then the voltage of the output terminal VOUT2 becomes 15 V. Further, since the load transistor 814 whose gate electrode is connected to the output terminal VOUT2 becomes a non-conductive state, then the output terminal VOUT1 maintains the voltage of 0 V.

Next, from the above-described state, the operation wherein the voltages of the input terminals VIN1 and VIN2 change respectively to 0 V and 3.3 V will be explained. When the voltages of the input terminals VIN1 and VIN2 change respectively to 0 V and 3.3 V, the input transistor 811 presents the conductive state, but the input transistor 812 presents a non-conductive state, respectively.

At this time, since the load transistor 814, which is connected to the drain electrode of the input transistor 812 becoming the conductive state, presents the conductive state, when the resistances at the conductive states of the input transistor 812 and the load transistor 814 are expressed by RON2 and RON4, the voltage VOUT2 of the output terminal VOUT2 at the time at which the voltage of the input terminal changes is expressed by the following formula 1.

$$V_{OUT2} = RON2 / (RON2 + RON4) \times VDD \quad (1)$$

As understood from the above-stated formula 1, the voltage of the output terminal VOUT2 at the time at which the voltage of the input terminal changes is determined by a divided voltage ratio between the resistances RON2 and RON4. With the above stated voltage, the load transistor 813 presents the conductive state and the voltage of the output terminal VOUT1 changes to 15 V. Since the voltage of the output terminal VOUT1 changes to 15 V, the resistance of the load transistor 814 increases, and finally the load transistor 814 presents a non-conductive state. As a result, the voltage of the output terminal VOUT2 becomes 0 V.

Herein, to shorten the time from when the conductive state of the input transistor 812 occurs to the time when the voltage of the output terminal VOUT2 becomes 0 V, it is necessary to make the voltage of the output terminal VOUT2 approach 0 V

as soon as possible by making the resistance value of the resistor RON2 small in the formula 1.

On the other hand, in the single phase input type level conversion circuit, one approach is employed using the differential input type level conversion circuit explained above, in which a single signal is inputted to one input terminal and a voltage having  $\frac{1}{2}$  of the single phase input amplitude is supplied to the other input terminal; or another approach is employed using the differential input type level conversion circuit explained above, in which a single signal is inputted to one input terminal and the single phase input amplitude is supplied to the other input terminal by reversing the single phase signal.

#### SUMMARY OF THE INVENTION

When the voltage between the drain electrode and the source electrode is constant, the drain current of a TFT or MOS transistor changes in proportion to a square of the effective gate voltage VE, which is a difference between the gate voltage and the threshold voltage Vth. Since the resistance RON, such as RON2 and RON4, under the above-stated conductive state is in inverse proportion to this drain current, the gate voltage increases abruptly in the vicinity of the threshold voltage Vth.

In the case of the above-described level conversion circuit 800, the drive condition of the gate voltages of the input transistors 811 and 812 corresponds to a voltage Vg1 between the gate electrode and the drain electrode of 2 V and a voltage Vg2 between the gate electrode and the drain electrode of 5.3 V.

To obtain the resistance under the conductive state necessary for a voltage Vg2 of 5.3 V, it is necessary to make the size of the input transistor large. When the size of the input transistor is made large, the capacity of the input terminal increases and also the capacity between the gate electrode and the drain electrode increases.

Further, since the input transistors 811 and 812 of the level conversion circuit 800 shown in FIG. 9 constitute a source ground type amplification circuit, the capacity between the gate electrode and the drain electrode is made large equivalently with a magnification of an amplification by the Miller effect. The increase in the equivalent load capacity becomes an obstacle to achieve high speed operation.

Further, the conventional single phase input type level conversion circuit is more complicated in comparison with the differential input type level conversion circuit. This means, for example, that, when an attempt is made to apply the single phase input type level conversion circuit to a digital type liquid crystal display apparatus, which is operated by an image signal in the form of a digital signal, the complexity becomes a large obstacle.

When an image is sent in the form of a digital signal, the data size thereof depends on the number of colors (a number of gray level) in the image signal, the pixel element number of the liquid crystal display apparatus, the frame frequency, and the operation frequency of the level conversion circuit. For example, in a case where the number of colors (number of gray level) requires 8 bits, the pixel element number is 1280×1024, the frame frequency is 60 Hz, and the operation frequency is 20 MHz, the input data size is about 32 bits.

An object of the present invention is to provide a liquid crystal display apparatus having a level conversion circuit which is able to carry out a high speed operation in the liquid crystal display apparatus.

Another object of the present invention is to provide a liquid crystal display apparatus having a level conversion

circuit which can be constituted by a small transistor capacity in the liquid crystal display apparatus.

According to the present invention, the above-stated objects can be attained in a liquid crystal display apparatus, wherein a level conversion circuit is provided for a signal circuit for driving the pixel elements of a display unit and a scanning circuit, the level conversion circuit is constituted of a first transistor and a second transistor in which the respective gate electrodes of the first transistor and the second transistor are connected to a first bias voltage power supply, and a third transistor and a fourth transistor in which respective gate electrodes of the third transistor and the fourth transistor are connected to a second bias voltage power supply and respective drain electrodes of the third transistor and the fourth transistor are connected to a power supply.

The respective drain electrodes of the first transistor and the second transistor are connected to respective drain electrodes of the third transistor and the fourth transistor, a signal having a mutually different polarity and having a low amplitude is inputted to the respective source electrodes of the first transistor and the second transistor, and from the drain electrode of the first transistor and the respective drain electrode of the first transistor and the second transistor, a signal having a mutually different polarity and having a high amplitude is taken out.

In accordance with the present invention, an output voltage is determined in accordance with a resistance ratio between the drain electrode and the source electrode of the first transistor and the second transistor in which respective gate electrodes are biased by the first bias voltage power supply and the third transistor and the fourth transistor in which respective gate electrodes are biased by the second bias voltage power supply.

Herein, a third resistor and a fourth resistor can be made large within an allowable range of operation speed. Further, since the respective gate electrodes of the first transistor and the second transistor are biased to a fixed voltage, the capacity between the drain electrode and the source electrode is not dependent on the amplification rate of the first transistor and the second transistor. As a result, the level conversion circuit according to the present invention can be operated at a high speed and the size of the transistor can be reduced.

#### BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a schematic diagram showing a level conversion circuit in a liquid crystal display apparatus representing a first embodiment according to the present invention;

FIG. 2 is a signal diagram showing an operation of the level conversion circuit in the liquid crystal display apparatus according to the present invention;

FIG. 3 is a schematic diagram showing a level conversion circuit in a liquid crystal display apparatus representing a second embodiment according to the present invention;

FIG. 4 is a schematic diagram showing a level conversion circuit in a liquid crystal display apparatus representing a third embodiment according to the present invention;

FIG. 5 is a schematic diagram showing a level conversion circuit in a liquid crystal display apparatus representing a fourth embodiment according to the present invention;

FIG. 6 is a schematic diagram a multi-input type level conversion circuit in a liquid crystal display apparatus representing a fifth embodiment according to the present invention;

FIG. 7 is a schematic diagram showing one example of a logic input circuit to which the level conversion circuit according to the present invention is applied;

FIG. 8 is a block diagram showing a liquid crystal display apparatus according to the present invention; and

FIG. 9 is a schematic diagram showing a differential input type level conversion circuit according to the prior art.

#### DESCRIPTION OF EXAMPLE EMBODIMENTS OF THE PRESENT INVENTION

Hereinafter, a liquid crystal display apparatus having a level conversion circuit representing one embodiment according to the present invention will be explained with reference to the drawings.

FIG. 1 shows a level conversion circuit in a liquid crystal display apparatus forming a first embodiment according to the present invention. The level conversion circuit is constituted by a level conversion unit 100 and a wave-form shaping unit 200.

The level conversion unit 100 is constituted by input transistors 111 and 112, load transistors 121 and 122, and bias transistors 131 and 132. In the level conversion unit 100, a respective gate electrode of the respective input transistors 111 and 112 is connected to a bias power supply VBIAS, a respective source electrode of the respective input transistors 111 and 112 is connected to input terminals VIN1 and VIN2, and a respective drain electrode of the respective input transistors 111 and 112 is connected to outputs Vo1 and Vo2, respectively.

In the level conversion unit 100, the gate electrodes of the respective load transistors 121 and 122 are connected in common to the bias use transistor 132, the source electrodes of the load transistors 121 and 122 are connected to a power supply VDD, and the drain electrodes of the respective load transistors 121 and 122 are connected to the outputs Vo1 and Vo2, respectively.

The gate electrode of the bias transistor 131 is connected to the bias power supply VBIAS, the source electrode of the bias transistor 131 is connected to a ground point, and the drain electrode of the bias transistor 131 is connected to the gate electrode and the drain electrode of the bias transistor 132. Herein, the bias transistor 132 and the load transistors 121 and 122 constitute a so-called current-miller circuit.

On the other hand, the wave-form shaping unit 200 is constituted by input transistors 213 and 214 and load transistors 211 and 212. Each of the input transistors 213 and 214 is provided in the form of a P-type transistor, and each of the load transistors 211 and 212 is provided in the form of a N-type transistor. In comparison with the circuit construction of the above-stated level conversion circuit 800 shown in FIG. 9, the circuit construction of the first embodiment according to the present invention is different in that the conductivity type of the transistor is reversed and the input voltage has a high amplitude. However, the circuit configuration of the first embodiment according to the present invention is otherwise similar to the level conversion circuit 800 of FIG. 9.

To the respective gate electrodes of a pair of the input transistors 111 and 112 of the level conversion unit 100, the signals VIN1 and VIN2 are supplied, and these signals VIN1 and VIN2 have a mutually opposite phase. The signal levels of these signals VIN1 and VIN2 have voltages with a low amplitude of, for example, 0 V and 3.3 V, the voltage of the power supply VDD is 15 V, and the voltage of the bias power supply VBIAS exceeds the maximum voltage of the input signals VIN1 and VIN2 and is 5.3 V, for example.

The operation of the level conversion circuit under the above-stated conditions in the liquid crystal display apparatus of the first embodiment according to the present invention will be explained with reference to FIG. 2. Herein, the

response of the output voltage Vo1 against the input signal VIN1 is shown. When the input signals VIN1 and VIN2 are 0 V and 3.3 V, respectively, the voltages VgsL and VgsH between the gate electrode and the source electrode of the input transistor 111 are 5.3 V and 2 V, respectively.

Since the resistance values RdsL and RdsH between the gate electrode and the source electrode of the input transistor 111, which corresponds to the above-stated voltages, have the relationship  $RdsL < RdsH$ , the output voltage Vo1 has a relationship of the same phase to the input signal VIN1. A high level output voltage VOH (when the input transistor 111 is in the non-conductive state) and a low level output VOL (when the input transistor 111 is in the conductive state) of the output voltage Vo1 at this time becomes a divided voltage between a resistance value RL1 between the drain electrode and the source electrode of the load transistor 121 and the resistance value RdsL or RdsH between the drain electrode and the source electrode of the input transistor 111. As a result, as shown in FIG. 2, the high level output voltage VOH is displaced a little from the power supply voltage VDD or the low level output VOL is displaced a little from the voltage of 0 V.

The response of the output voltage Vo2 relative to the input signal VIN2 is not shown in the figure, but the response of the output voltage Vo2 has a relationship of the reverse phase of the response of the input signal VIN1. Namely, the relationship between the input signals VIN1 and VIN2 of the level conversion unit 100 and the output voltages Vo1 and Vo2 of the level conversion unit 100 has the same phase. As a result, the output voltage Vo1 is displaced a little from the power supply voltage VDD and the output voltage Vo2 is displaced a little from 0 V.

Next, as stated above, the wave-form shaping unit 200 is constituted by the input transistors 213 and 214 and the load transistors 211 and 212. The respective input transistors 213 and 214 are provided in the form of a P-type TFT, and the respective load transistors 211 and 212 are provided in the form of a N-type TFT. The respective gate electrodes of the input transistors 213 and 214 are connected to the respective output terminals Vo1 and Vo2 of the level conversion circuit 100, respectively; the respective drain electrodes of the input transistors 213 and 214 are connected to the output terminals VOUT1 and VOUT2, respectively; and the respective source electrodes of the input transistors 213 and 214 are connected to the power supply voltage VDD, respectively.

Further, the respective drain electrodes of the load transistors 211 and 212 are connected to respective output terminals VOUT1 and VOUT2, respectively; the respective gate electrodes of the load transistors 211 and 212 are connected to the output terminals VOUT1 and VOUT2, respectively; and the respective source electrodes of the load transistors 211 and 212 are connected to the ground point, respectively.

The wave-form shaping unit 200 uses a different conductivity type of transistor than that constituted by the input transistors 811 and 812 and the load transistors 813 and 814 in the circuit of FIG. 9, but is otherwise similar in configuration thereto.

The difference in construction of this first embodiment according to the present invention in comparison with the circuitry shown in FIG. 9 is as follows. Namely, the input signal is amplified in the level conversion unit 100 and has an amplitude which is substantially equal to the amplitude of the power supply voltage. As a result, it is unnecessary to make the size of the transistor large, which is a problem in the prior art, and thus it is possible to carry out a high speed operation.

More specifically, in the level conversion circuit for use in a liquid crystal display apparatus according to the present invention, by using the bias power supply VBIAS, the gate

voltage for the input transistors **111** and **112** is controlled in accordance with the voltage of the bias power supply VBIAS. For the above-stated reasons, it is possible to make the current level of the drain current operation points of the input transistors **111** and **112** and the drain current operation points of the load transistors **121** and **122** high, and so it is possible to carry out a high speed operation.

Further, since the relationship between the input and the output involves the same phase, an increase in the capacity can be prevented according to the miller effect and with this point, it is possible to carry out a high speed operation.

In the level conversion circuit for use in the liquid crystal display apparatus of this first embodiment according to the present invention, since the level conversion circuit is constituted of only transistors, it has the advantage that the level conversion circuit can be manufactured easily.

Further, in the level conversion circuit for use in the liquid crystal display apparatus of this first embodiment according to the present invention, the bias transistor **131** and the input transistors **111** and **112** are constituted mutually of N-type transistors and the currents of the load transistors **121** and **122** are controlled in accordance with the bias transistor **132** and the output voltage is generated through this current and the resistances of the input transistors **111** and **112**.

As a result, the fluctuation of the output voltage relative to the fluctuation of the characteristic of the transistor can be restrained, resulting in the advantage that the yield in the manufacturing can be heightened.

FIG. 3 shows a level conversion circuit in a liquid crystal display apparatus representing a second embodiment according to the present invention. This second embodiment according to the present invention differs from the first embodiment shown in FIG. 1, and the difference is in the wave-form shaping unit **200** shown in FIG. 3.

The wave-form shaping unit **200** of this second embodiment according to the present invention is constituted of N-type load transistors **221** and **222** and P-type input transistors **223** and **224**. The respective source electrodes of the N-type load transistors **221** and **222** are grounded, the respective gate electrodes of the load transistors **221** and **222** are connected to the input terminals VIN1 and VIN2, and the respective drain electrodes of the load transistors **221** and **222** are connected to the respective drain electrodes of the P-type input transistors **223** and **224**, respectively.

The respective source electrodes of the P-type input transistors **223** and **224** are connected to the power supply VDD and the respective gate electrodes of the input transistors **223** and **224** are connected to the outputs Vo1 and Vo2 of the level conversion unit **100**, respectively.

The operation of the wave-form shaping unit **200** constituted as described above will be explained. As one example of the conditions of operation, when the voltages of the input terminals VIN1 and VIN2 are respectively 3.3 V and 0 V, the voltage of the power supply VDD is 15 V, and the voltage of the bias power supply is 5.3 V. In this case, the gate electrodes of the N-type load transistors **221** and **222** receive voltages of 3.3 V and 0 V, respectively, and the load transistor **221** is in the conductive state and the load transistor **222** is in the non-conductive state.

On the other hand, the gate electrodes of the P-type input transistors **223** and **224**, to which the output of the level conversion unit **100** is inputted, receive the voltages of substantially 15 V and substantially 0 V, so that the load transistor **221** is in the conductive state and the load transistor **222** is in the non-conductive state.

As a result, the output terminals VOUT1 and VOUT2 become respectively 0 V and 15 V, and the low amplitude

voltage signals of 3.3 V and 0 V are converted to high amplitude voltage signals of 0 V and 15 V.

According to the level conversion circuit in the liquid crystal display apparatus of the second embodiment according to the present invention, since each of the gate electrodes of the N-type load transistors and the gate electrodes of the P-type input transistors constituting the wave-form shaping unit **200** are controlled independently at 0.5 V and 15 V as a standard, there is the advantage that the level conversion circuit can be operated suitably relative to the fluctuation of the power supply voltage VDD.

FIG. 4 shows a level conversion circuit in a liquid crystal display apparatus representing a third embodiment according to the present invention. This third embodiment differs from the first embodiment shown in FIG. 1, and the difference is in the wave-form shaping unit **200**.

The wave-form shaping unit **200** of this third embodiment according to the present invention is constituted of N-type load transistors **231** and **232** and P-type input transistors **233** and **234**. Each of the N-type load transistor **231** and the P-type input transistor **233** and each of the N-type load transistor **232** and the P-type input transistor **234** constitutes, respectively, an inverter circuit.

The operation of the wave-form shaping unit **200** constituted as described above will be explained. As one example of the conditions of operation, the voltages of the input terminals VIN1 and VIN2 are respectively 3.3 V and 0 V, the voltage of the power supply VDD is 15 V and the voltage of the bias power supply is 5.3 V in this case, the respective input transistors **111** and **112** are respectively in the conductive state and the non-conductive state, and the output voltages Vo1 and Vo2 of the level conversion circuit **100** are substantially 15 V and substantially 0 V. Since these output voltages are subjected to wave-form shaping and are amplified in the inverter circuit, the voltages of the output terminals VOUT1 and VOUT2 become respectively 0 V and 15 V.

According to the level conversion circuit **100** in the liquid crystal display apparatus of this third embodiment according to the present invention, the low amplitude voltage signals of 3.3 V and 0 V, which are supplied to the input terminals, can be converted to high amplitude voltage signals of 0 V and 15 V.

FIG. 5 shows a level conversion circuit in a liquid crystal display apparatus representing a fourth embodiment according to the present invention. This fourth embodiment differs from the first embodiment shown in FIG. 1, and the difference is in the level conversion unit **100**. The level conversion unit **100** of this fourth embodiment according to the present invention is constituted of resistors **141** and **142** in place of the load transistors **121** and **122**, which are employed in the first embodiment shown in FIG. 1.

The operation of the level conversion unit **100** constituted by the fourth embodiment according to the present invention will be explained. As one example of the conditions of operation, the voltages of the input terminals VIN1 and VIN2 are respectively 3.3 V and 0 V, the voltage of the power supply VDD is 15 V and the voltage of the bias power supply is 5.3 V. In this case, the respective input transistors **111** and **112** are respectively in the conductive state and the non-conductive state.

As a result, the output voltages Vo1 and Vo2 of the level conversion circuit **100** are substantially 15 V and substantially 0 V, respectively. Since these output voltages are carried subjected to wave-form shaping in the wave-form shaping unit **200**, the voltages of the output terminals VOUT1 and VOUT2 become respectively 0 V and 15 V.

According to the level conversion circuit **100** in the liquid crystal display apparatus of this fourth embodiment according to the present invention, the low amplitude voltage signals of 3.3 V and 0 V, which are supplied to the input terminals VIN1 and VIN2, can be converted to the high amplitude voltage signals of 0 V and 15 V.

FIG. 6 shows a level conversion circuit in a liquid crystal display apparatus representing a fifth embodiment according to the present invention, in the form of a multi-input type level conversion circuit. The level conversion circuit of this fifth embodiment is one in which the level conversion unit of the second embodiment according to the present invention shown in FIG. 3 is formed with a multi-input type level conversion circuit.

A level conversion circuit **500** of this fifth embodiment according to the present invention is constituted of a N number of input transistors **511-51N**, and a N number of load transistors **521-52N**, along with bias transistors **531** and **541**. The respective source electrodes of the input transistors **511-51N** are connected to a N number of input terminals **V11-V1N** (N) and the respective drain electrodes of the input transistors **511-51N** are connected to the respective drain electrodes of the N number of load transistors **521-52N** and to a N number of output terminals **VO1-VO(N)**.

In the level conversion circuit **500** of this fifth embodiment according to the present invention, by adding two transistors, including an input transistor and a load transistor, to the level conversion circuit **500**, an effect is achieved in which the number of inputs can be increased.

FIG. 7 shows one embodiment of a logic input circuit in which the level conversion circuit according to the present invention is employed. The logic input circuit of this embodiment according to the present invention is constituted of the differential input type level conversion circuit **100**, the multi-input type level conversion circuit **500**, and a latch circuit unit **600** comprised of N number of latch circuits **611-61(N)**.

Herein, in the differential input type level conversion circuit **100**, differential clock signals **CK1** and **CK2** having a low voltage amplitude are inputted and differential clock signals which are converted to the high voltage amplitude are outputted to the latch circuits **611-61N**. In the multi-input type level conversion circuit **500**, a N number of data signals **DI-D(N)** having a low voltage amplitude are inputted and the data signals **DI-D(N)** which are converted to the high voltage amplitude are outputted to the respective latch circuits **611-61N**.

In the respective latch circuits of the latch circuit unit **600**, a clock signal having a high voltage amplitude and a data signal having a high voltage amplitude are inputted and the respective latch circuits are operated, and then a N number of latch data **01-0(N)** are outputted.

FIG. 8 is one example of a system for a liquid crystal display apparatus which incorporates the features according to the present invention. This liquid crystal display apparatus is constituted by an image signal generation apparatus **80**, an image signal processing circuit **60**, a timing control circuit **70**, and a liquid crystal display panel **10**.

Herein, the liquid crystal display panel **10** is constituted by a display unit **20** which is comprised of plural pixel elements arranged with a matrix form, a signal circuit **30** and a scanning circuit **40** for driving these pixel elements, a differential input type level conversion circuit **700**, multi-input type level conversion circuits **500a** and **500b**, and a data latch circuit **600**.

Among these elements, the differential input type level conversion circuit **700** is constituted by the level conversion unit **100** and the wave-form shaping unit **200**, examples of which have been described with reference to the first embodi-

ment to the fourth embodiment according to the present invention. The multi-input type level conversion circuits **500a** and **500b** correspond to the multi-input type level conversion circuit **500**, which has been described as the fifth embodiment according to the present invention; and further, the data latch circuit **600** corresponds to the latch circuit unit **600** shown in FIG. 7.

The operation of the system of the liquid crystal display apparatus constituted as described above will be explained. In the image signal generation apparatus **80**, an image signal **81** is outputted to the image signal conversion circuit **60**, and a clock signal **85**, a horizontal synchronization signal **86** and a vertical synchronization signal **87** are inputted to the timing control circuit **70**.

In the image signal conversion circuit **60**, the signal frequency of the inputted image signal **81** is lowered according to a serial-parallel conversion processing, and n-parallel image signals **D1-Dn** are formed; and further, these image signals **D1-Dn** are outputted to the multi-input type level conversion circuit **500a** of the liquid crystal display panel **10**. These image signals **D1-Dn** are converted to high amplitude signals by the multi-input type level conversion circuit **500a** and are stored into the data latch circuit **600**. The data latch circuit **600** operates to output these stored signals having the high amplitude **HD1-HDn** into the signal circuit **30**.

On the other hand, in the timing control circuit **70**, in accordance with the inputted clock signal **85**, the inputted horizontal synchronization signal **86** and the inputted vertical synchronization signal **87**, a clock signal **71** for taking in the image signals **D1-Dn** is outputted to the differential input type level conversion circuit **700** of the liquid crystal display panel **10**, and further control signals **72-75** for driving the scanning circuit **40** and the signal circuit **30** are outputted to the multi-input type level conversion circuit **500b** of the liquid crystal display panel **10**.

The differential input type level conversion circuit **700** converts the clock signal **71** to a high amplitude clock signal and outputs the converted clock signal to the data latch circuit **600**. The multi-input type level conversion circuit **500b** converts the control signals **72-75** to a clock signal **HCK** for controlling the signal circuit **30**, a start signal **HST**, a clock signal **VCK** for controlling the scanning circuit **40**, and a start signal **VST**. The display unit **20** is controlled in accordance with the outputs of the signal circuit **20** and the scanning circuit **40** and displays images which correspond to the image signals **D1-Dn**.

In the liquid crystal display apparatus constituted as described above, the level conversion circuit is comprised of the level conversion unit **100** and the wave-form shaping unit **200**, examples of which have been described with reference to the first embodiment to the fourth embodiment according to the present invention, and the multi-input type level conversion circuit **500** represented by the fifth embodiment according to the present invention.

Accordingly, the input of the liquid crystal display panel **10** can be formed with a low amplitude, and the output circuits of the image signal processing circuit **60** and also the timing control circuit **70** can be constituted simply. Further, an unnecessary radiation of electromagnetic waves can be reduced.

Further, in the embodiments according to the present invention, examples using TFT devices were described, however, it is possible to obtain the same effects using monocrystallization silicon form MOS transistors. Further, the embodiments according to the present invention can achieve the same effects when the N conductive type transistor and the P conductive type transistor are interchanged therein.

Further, according to the bias power supply of the level conversion circuit, since the drain current operation point of the input transistor and the drain current operation point of the load transistor can be formed with a high current, high speed operation in the level conversion circuit can be attained, and, further, the size of the transistor can be reduced.

Further, since the level conversion circuit is constituted using only transistors, the level conversion circuit can be manufactured easily. Further, since the current of the load transistor is controlled according to the operation of the bias transistor and the output voltage can be generated through the above-stated current and resistance of the input transistor, the fluctuation of the output voltage relative to the fluctuation of the characteristic of the transistor can be restrained, and, as a result, the yield in the manufacture of the level conversion circuit can be heightened.

The level conversion circuit according to the present invention is used as both the signal circuit and the scanning circuit for driving the pixel elements of the display unit of the liquid crystal display apparatus. Of course, the level conversion circuit according to the present invention can be used in only one of the signal circuit and the scanning circuit as well.

What is claimed is:

1. A display apparatus comprising:

a display unit comprised of pixel elements arranged in a matrix;

a signal circuit and a scanning circuit for driving the pixel elements;

a first type level conversion circuit connected to at least one of the signal circuit and the scanning circuit, to perform level conversion of data signals and transmit to the signal circuit and the scanning circuit to drive the pixel elements; and

a second level conversion circuit connected to at least one of the signal circuit and the scanning circuit, to perform level conversion of differential clock signals to control the transmission of data signals to the signal circuit to drive the pixel elements,

wherein a differential input type level conversion circuit includes a level conversion unit comprising:

a first transistor and a second transistor connected in parallel, having respective gate electrodes coupled to receive a bias voltage; and

a first resistance element and a second resistance element connected in parallel, and disposed between respective drain electrodes of the first transistor and the second transistor and a power supply terminal;

wherein respective source electrodes of the first transistor and the second transistor are coupled to receive clock signals having a mutually different polarity and a low voltage amplitude, and the respective drain electrodes of the first transistor and the second transistor are coupled to output clock signals having a mutually different polarity and a high voltage amplitude.

2. A display apparatus according to claim 1,

wherein the second level conversion circuit includes a waveform shaping unit for shaping a waveform of clock signals having said higher voltage amplitude, and comprising:

a third transistor and a fourth transistor connected in parallel, having respective gate electrodes connected to respective drain electrodes of the first transistor and the second transistor, and

a fifth transistor and a sixth transistor connected in parallel, having respective drain electrodes connected to respective drain electrodes of the third transistor and the fourth

transistor, and having respective source electrodes connected to a ground terminal,

wherein respective source electrodes of the third transistor and the fourth transistor are coupled to a power supply terminal, and respective gate electrodes of the fifth transistor and the sixth transistor are connected to respective drain electrodes of the sixth transistor and the fifth transistor.

3. A display apparatus according to claim 1,

wherein the bias voltage is equal to a sum of a peak voltage of clock signals having the low voltage amplitude and a threshold voltage of the first transistor and the second transistor.

4. A display apparatus comprising:

a display unit comprised of pixel elements arranged in a matrix;

a signal circuit and a scanning circuit for driving the pixel elements;

a first level conversion circuit connected to the signal circuit and the scanning circuit, to perform level conversion of data signals and transmit to the signal circuit and the scanning circuit to drive the pixel elements; and

a second level conversion circuit connected to at least one of the signal circuit and the scanning circuit, to perform level conversion of differential clock signals to control the transmission of data signals to the signal circuit to drive the pixel elements, wherein a differential input type level conversion circuit comprises:

a plurality of transistors each having a gate electrode coupled to receive to a bias voltage; and

a plurality of resistance elements each connected between a drain electrode of a respective transistor and a power supply terminal;

wherein each of a plurality of input pixel element drive signals is inputted to the source electrode of a respective one of the transistors;

wherein each of control signals is outputted from the drain electrode of a respective transistor; and

wherein amplitudes of output control signals are higher than amplitudes of input control signals.

5. A display apparatus according to claim 4,

wherein each resistance element is comprised of a transistor having a gate electrode biased to the bias voltage.

6. A display panel comprising:

a display unit comprised of pixel elements arranged in a matrix;

a scanning circuit and a signal circuit arranged to drive pixel elements;

a first level conversion circuit arranged to generate control signals and to convert image signals having a low voltage amplitude into image signals having a high voltage amplitude;

a second level conversion circuit arranged to convert differential clock signals having a low voltage amplitude into clock signals having a high voltage amplitude; and

a latch circuit arranged to latch the image signals having the high voltage amplitude to the signal circuit in accordance with the clock signals having the high voltage amplitude;

wherein, the signal circuit and the scanning circuit are driven to provide a visual display of images corresponding to the image signals latched from the latch circuit in accordance with the control signals generated from the first level conversion circuit.

13

7. A display panel according to claim 6,  
 wherein the second level conversion circuit comprises:  
 a first transistor and a second transistor connected in parallel,  
 having respective gate electrodes coupled to receive a bias voltage; and  
 a first resistance element and a second resistance element  
 connected in parallel, and disposed between respective  
 drain electrodes of the first transistor and the second  
 transistor and a power supply terminal;  
 wherein respective source electrodes of the first transistor  
 and the second transistor are coupled to receive clock  
 signals having a mutually different polarity and a low  
 voltage amplitude, and the respective drain electrodes of  
 the first transistor and the second transistor are coupled  
 to output clock signals having a mutually different polarity  
 and a high voltage amplitude.

8. A display panel according to claim 7,  
 wherein the second level conversion circuit includes a  
 waveform shaping unit for shaping a waveform of clock  
 signals having the high voltage amplitude, and comprising:  
 a third transistor and a fourth transistor connected in parallel,  
 having respective gate electrodes connected to  
 respective drain electrodes of the first transistor and the  
 second transistor, and  
 a fifth transistor and a sixth transistor connected in parallel,  
 having respective drain electrodes connected to respective  
 drain electrodes of the third transistor and the fourth  
 transistor, and having respective source electrodes connected  
 to a ground terminal,  
 wherein respective source electrodes of the third transistor  
 and, the fourth transistor are coupled to a power supply  
 terminal, and respective gate electrodes of the fifth transistor  
 and the sixth transistor are connected to respective  
 drain electrodes of the sixth transistor and the fifth transistor.

9. A display panel according to claim 8,  
 wherein the bias voltage is equal to a sum of a peak voltage  
 of clock signals having the low voltage amplitude and a  
 threshold voltage of the first transistor and the second  
 transistor.

10. A display panel according to claim 6,  
 wherein the second level conversion circuit comprises:  
 a plurality of transistors each having a gate electrode  
 coupled to receive a bias voltage; and  
 a plurality of resistance elements each connected between  
 a drain electrode of a respective transistor and a power  
 supply terminal;  
 wherein each of the control signals is inputted to a source  
 electrode of a respective transistor;  
 wherein each of the control signals is outputted from the  
 drain electrode of a respective transistor; and  
 wherein amplitudes of the output control signals are higher  
 than amplitudes of the input control signals.

14

11. A display panel according to claim 10,  
 wherein each resistance element is comprised of a transistor  
 having a gate electrode biased to a bias voltage.

12. A display panel according to claim 11,  
 wherein the bias voltage is equal to a sum of a peak voltage  
 of the input control signals and a threshold voltage of the  
 transistors.

13. A display apparatus comprising:  
 a display unit comprised of pixel elements arranged in a  
 matrix;  
 a signal circuit and a scanning circuit for driving the pixel  
 elements;  
 a first level conversion circuit to perform level conversion  
 of data signals;  
 a second level conversion circuit connected to at least one  
 of the signal circuit and the scanning circuit, to perform  
 level conversion of differential clock signals to control  
 the transmission of data signals to the signal circuit to  
 drive the pixel elements; and  
 a latch circuit connected to the first level conversion circuit  
 and the second level conversion circuit, to latch the data  
 signals transmitted from the first level conversion circuit  
 to the signal circuit in accordance with clock signals  
 outputted from the second level conversion circuit;  
 wherein:  
 the second conversion circuit converts the differential  
 clock signals having a low voltage amplitude into clock  
 signals having a high voltage amplitude, and outputs the  
 clock signals having the high voltage amplitude to the  
 latch circuit.

14. A display apparatus according to claim 13,  
 wherein the first level conversion circuit connected to at  
 least one of the signal circuit and the scanning circuit,  
 transmits to the signal circuit and the scanning circuit to  
 drive the pixel elements.

15. A display apparatus according to claim 13,  
 wherein the first level conversion circuit converts input  
 data signals having a low voltage amplitude to data  
 signals having a high voltage amplitude, and outputs the  
 data signals having the high voltage amplitude to the  
 latch circuit.

16. A display apparatus according to claim 13,  
 wherein the first level conversion circuit and the second  
 level conversion circuit has a plurality of thin film transistors.

17. A display apparatus according to claim 16,  
 wherein the thin film transistor has multi-crystallization  
 silicon.

18. A display apparatus according to claim 16,  
 wherein the first level conversion circuit has a plurality of  
 input terminals and a plurality of output terminals,  
 the number of input terminals is same as the number of  
 output terminals.

\* \* \* \* \*

专利名称(译)	具有电平转换电路的液晶显示装置		
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摘要(译)

本发明提供一种液晶显示装置，其具有能够获得高速操作并且还能够获得小晶体管容量的电平转换电路。在液晶显示装置中，提供了用于驱动显示单元的像素元件的信号电路和扫描电路。电平转换电路由第一和第二晶体管111和112以及第三和第四晶体管121和122构成，其中各个栅电极连接到第一偏置电压电源，第三和第四晶体管121和122中连接有相应的栅电极第二偏压电源和各个源极连接到电源。

